



## Features

- 2000 Watts Peak Pulse Power per Line ( $t_p = 8/20\mu s$ )
- Replacement for MLV (0805)
- Protects one I/O or power line
- Low Clamping Voltage
- Working Voltage: 7V
- Low Leakage Current



SOD-323F

## IEC Compatibility (EN61000-4)

- IEC 61000-4-2 (ESD)  $\pm 30kV$  (air),  $\pm 30kV$  (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 100A (8/20 $\mu s$ )

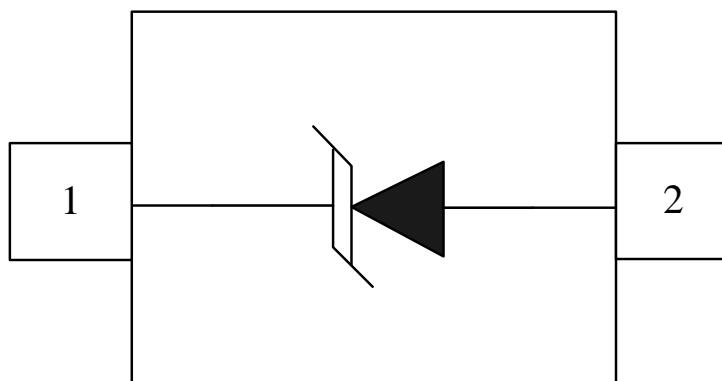
## Mechanical Characteristics

- JEDEC SOD-323F package
- Packaging : Tape and Reel per EIA 481
- RoHS Compliant

## Applications

- Laptop Computers
- Cellular Phones
- Digital Cameras
- Personal Digital Assistants (PDAs)

## Schematic & PIN Configuration



SOD-323F (Top View)

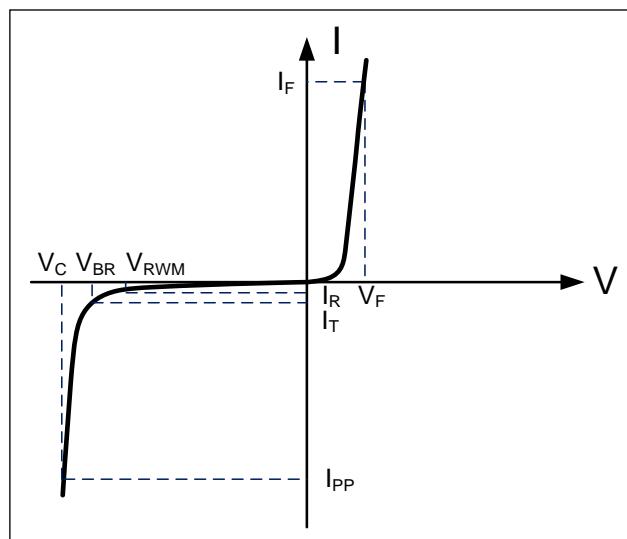


### Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ( $t_p = 8/20\mu s$ )	$P_{PP}$	2000	Watts
Peak Pulse Current ( $t_p = 8/20\mu s$ )	$I_{PP}$	100	A
Operating Temperature	$T_J$	-55 to +125	°C
Storage Temperature	$T_{STG}$	-55 to +150	°C

### Electrical Parameters (T=25°C)

Symbol	Parameter
$I_{PP}$	Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Reverse Stand-Off Voltage
$I_R$	Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$I_F$	Forward Current
$V_F$	Forward Voltage @ $I_F$



### Electrical Characteristics

DW07D3HP-S						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	$V_{RWM}$				7.0	V
Reverse Breakdown Voltage	$V_{BR}$	$I_T=1\text{mA}$	7.7			V
Reverse Leakage Current	$I_R$	$V_{RWM}=7\text{V}, T=25^\circ\text{C}$			200	nA
Forward Voltage	$V_F$	$I_F=10\text{mA}$	0.6		1.0	V
Clamping Voltage	$V_C$	$I_{PP}=100\text{A}, t_p=8/20\mu\text{s}$		16	20	V
Dynamic Resistance <sup>1,2</sup>	$R_{DYN}$	$\text{TLP}=0.2/100\text{ns}$		0.12		Ω
ESD Clamping Voltage <sup>1</sup>	$V_C$	$I_{PP} = 4\text{A}, t_p = 0.2/100\text{ns} (\text{TLP})$		8.7		V
ESD Clamping Voltage <sup>1</sup>	$V_C$	$I_{PP} = 16\text{A}, t_p = 0.2/100\text{ns} (\text{TLP})$		10.1		V
Junction Capacitance	$C_j$	$V_R = 0\text{V}, f = 1\text{MHz}$		700	1000	pF

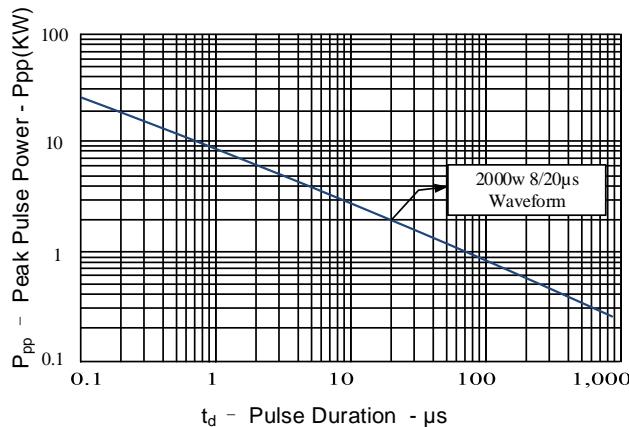
Notes : 1、TLP Setting :  $t_p=100\text{ns}$ ,  $t_i=0.2\text{ns}$ ,  $I_{TLP}$  and  $V_{TLP}$  sample window: $t_1=70\text{ns}$  to  $t_2=90\text{ns}$ .

2、Dynamic resistance calculated from  $I_{PP}=4\text{A}$  to  $I_{PP}=16\text{A}$  using "Best Fit".

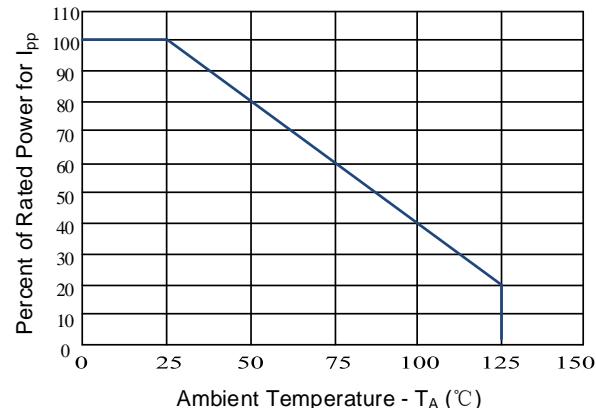


## Typical Characteristics

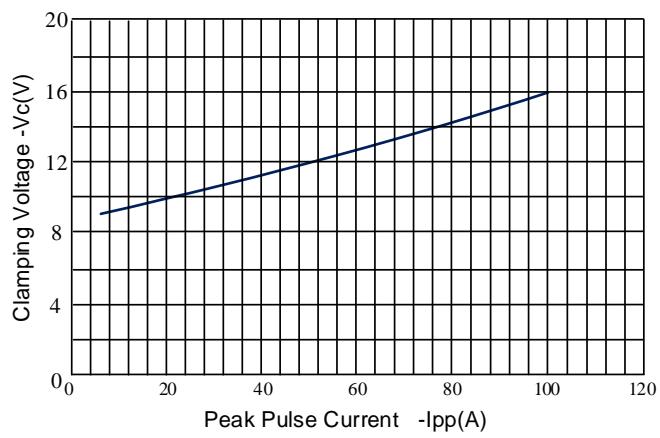
**Figure 1: Peak Pulse Power vs. Pulse Time**



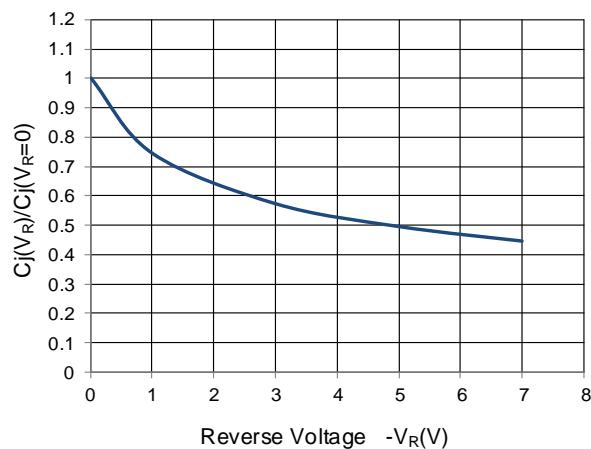
**Figure 2: Power Derating Curve**



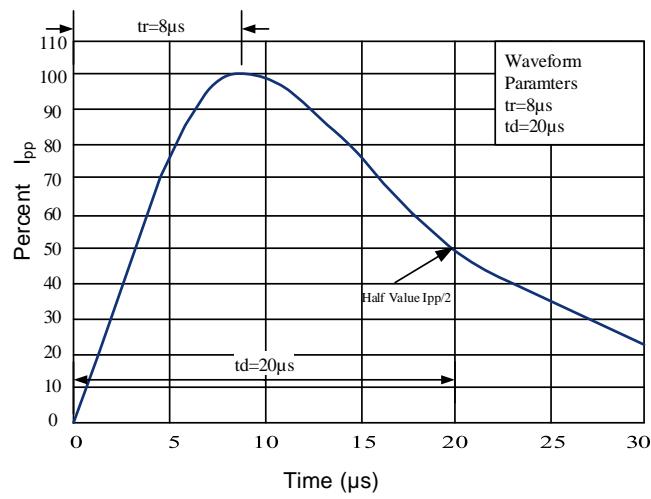
**Figure 3: Clamping Voltage vs. Peak Pulse Current**



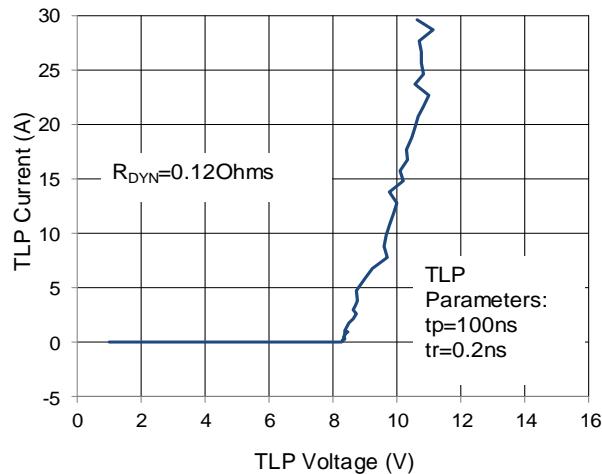
**Figure 4: Normalized Junction Capacitance vs. Reverse Voltage**



**Figure 5: 8/20μs Pulse Waveform**



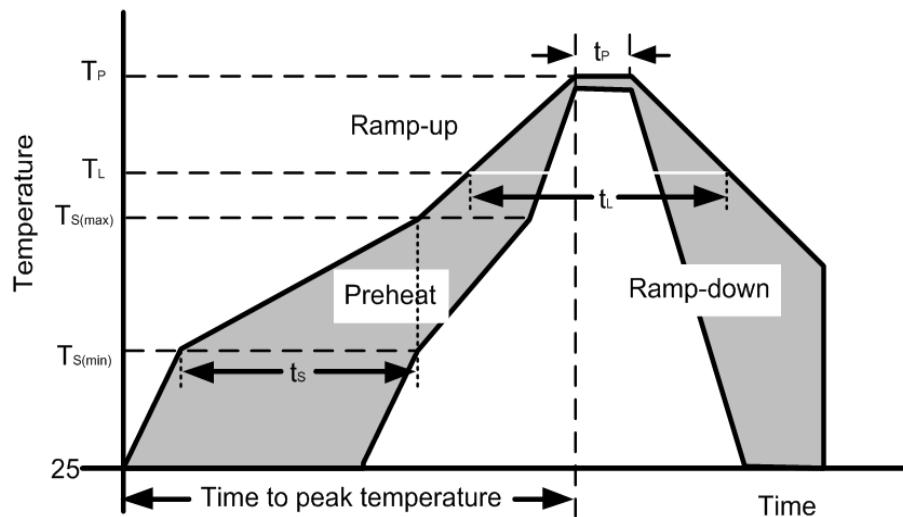
**Figure 6: TLP Curve**





## Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	Temperature Min ( $T_{s(min)}$ )	150°C
	Temperature Max ( $T_{s(max)}$ )	200°C
	Time (min to max) (ts)	60 – 190 secs
Average ramp up rate (Liquidus Temp) ( $T_L$ ) to peak		5°C/second max
$T_{S(max)}$ to $T_L$ —Ramp-up Rate		5°C/second max
Reflow	Temperature ( $T_L$ ) (Liquidus)	217°C
	Temperature ( $t_L$ )	60 – 150 seconds
	Peak Temperature ( $T_P$ )	260+0/-5 °C
Time within actual peak Temperature ( $t_p$ )		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature ( $T_P$ )		8 minutes Max.
Do not exceed		280°C





## Outline Drawing – SOD-323F

PACKAGE OUTLINE		SOD-323F		
SYMBOL	MILLIMETERS			
	MIN	TYP	MAX	
A	0.60	0.65	0.75	
b	0.25	0.30	0.40	
C	0.06	0.13	0.21	
D	1.60	1.70	1.80	
E	1.15	1.25	1.35	
H <sub>E</sub>	2.30	2.50	2.70	
L	0.30	0.40	0.50	

	<b>Notes:</b> Controlling Dimension: Millimeter.
<b>DIMENSIONS: MILLIMETERS</b>	

## Marking Codes

Part Number	Marking Code
DW07D3HP-S	

## Package Information

Qty: 3k/Reel